NSN 5962-01-293-1165

Memory Microcircuit - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5962-01-293-1165

Body Length:
Between 1.150 inches and 1.290 inches
Body Width:
Between 0.480 inches and 0.610 inches
Body Height:
Between 0.085 inches and 0.250 inches
Operating Tempurature Range:
+0.0/+70.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Schottky and 3-state output and programmable and hermetically sealed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Time Rating Per Chacteristic:
55.00 nanoseconds propagation delay time, low to high level output and 55.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
24 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig: